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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	160
Number of Logic Elements/Cells	1280
Total RAM Bits	65536
Number of I/O	63
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 85°C (TA)
Package / Case	81-VFBGA, CSPBGA
Supplier Device Package	81-CSBGA (5x5)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/ice65l01f-tcb81i

Overview

The Lattice Semiconductor iCE65 programmable logic family is specifically designed to deliver the lowest static and dynamic power consumption of any comparable CPLD or FPGA device. iCE65 devices are designed for cost-sensitive, high-volume applications and provide on-chip, nonvolatile configuration memory (NVCM) to customize for a specific application. iCE65 devices can self-configure from a configuration image stored in an external commodity SPI serial Flash PROM or be downloaded from an external processor over an SPI-like serial port.

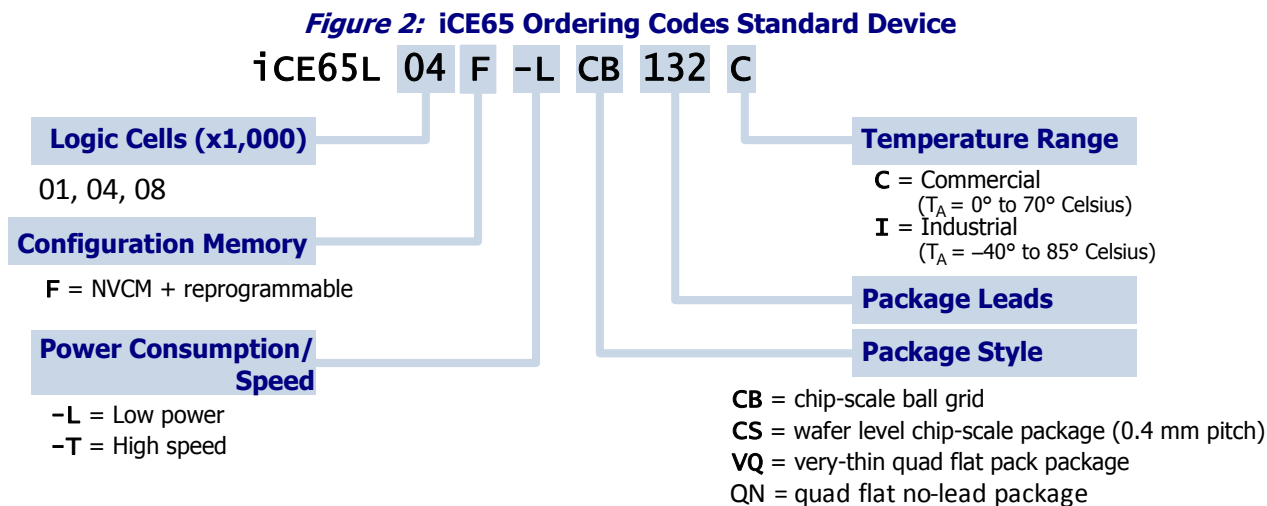
The three iCE65 components, highlighted in [Table 1](#), deliver from approximately 1K to nearly 8K logic cells and flip-flops while consuming a fraction of the power of comparable programmable logic devices. Each iCE65 device includes between 16 to 32 RAM blocks, each with 4Kbits of storage, for on-chip data storage and data buffering.

As pictured in [Figure 1](#), each iCE65 device consists of four primary architectural elements.

- An array of Programmable Logic Blocks (PLBs)
 - ◆ Each PLB contains eight Logic Cells (LCs); each Logic Cell consists of ...
 - A fast, four-input look-up table (LUT4) capable of implementing any combinational logic function of up to four inputs, regardless of complexity
 - A 'D'-type flip-flop with an optional clock-enable and set/reset control
 - Fast carry logic to accelerate arithmetic functions such as adders, subtracters, comparators, and counters.
 - ◆ Common clock input with polarity control, clock-enable input, and optional set/reset control input to the PLB is shared among all eight Logic Cells
- Two-port, 4Kbit RAM blocks (RAM4K)
 - ◆ 256x16 default configuration; selectable data width using programmable logic resources
 - ◆ Simultaneous read and write access; ideal for FIFO memory and data buffering applications
 - ◆ RAM contents pre-loadable during configuration
- Four I/O banks with independent supply voltage, each with multiple Programmable Input/Output (PIO) blocks
 - ◆ LVCMOS I/O standards and LVDS outputs supported in all banks
 - ◆ I/O Bank 3 supports additional SSTL, MDDR, LVDS, and SubLVDS I/O standards
- Programmable interconnections between the blocks
 - ◆ Flexible connections between all programmable logic functions
 - ◆ Eight dedicated low-skew, high-fanout clock distribution networks

Ordering Information

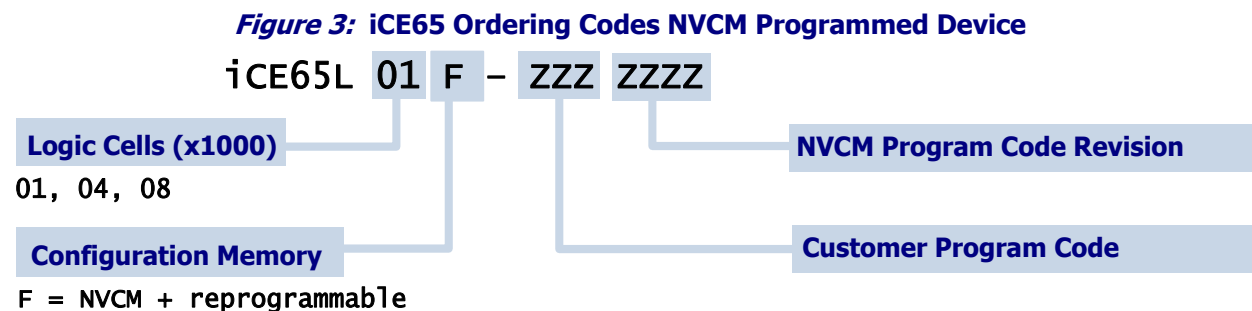
Figure 2 describes the iCE65 ordering codes for all packaged, non-NVCM Programmed components. See the separate DiePlus data sheets when ordering die-based products.



iCE65 devices offer two power consumption, speed options. Standard products (“-L” ordering code) have low standby and dynamic power consumption. The “-T” provides higher-speed logic.

Similarly, iCE65 devices are available in two operating temperature ranges, one for typical commercial applications, the other with an extended temperature range for industrial and telecommunications applications. The ordering code also specifies the device package option, as described further in Table 2.

Figure 3 describes the iCE65 ordering codes for all packaged, NVCM Programmed components.



Implementing Subtractors, Decrementers

As mentioned earlier, the Carry Logic generates a High output whenever the sum of $I1 + I2 + \text{CARRY_IN}$ generates a carry. The Carry Logic does not specifically have a subtract mode. To implement a subtract function or decrement function, logically invert either the $I1$ or $I2$ input and invert the initial carry input. This performs a 2s complement subtract operation.

Figure 6: Two-bit Adder Example

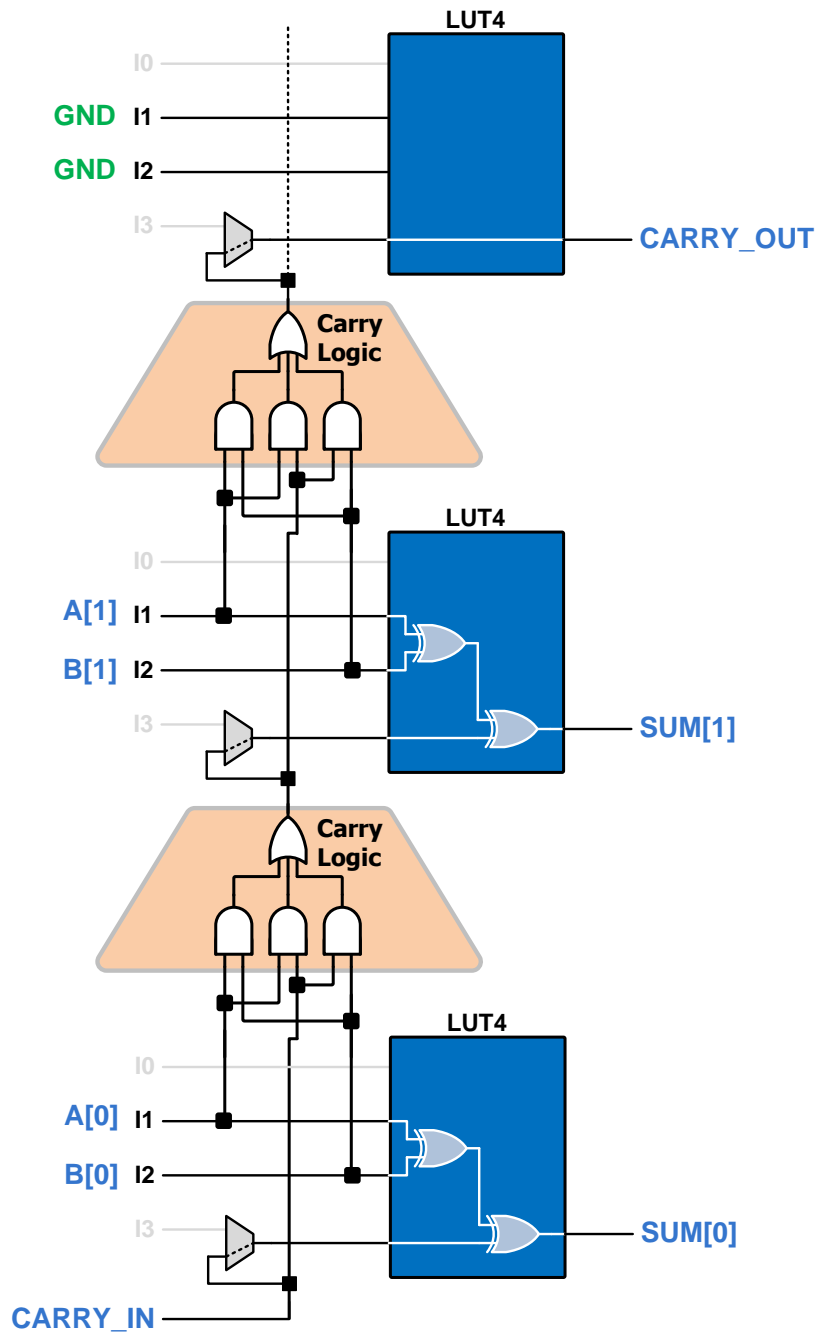
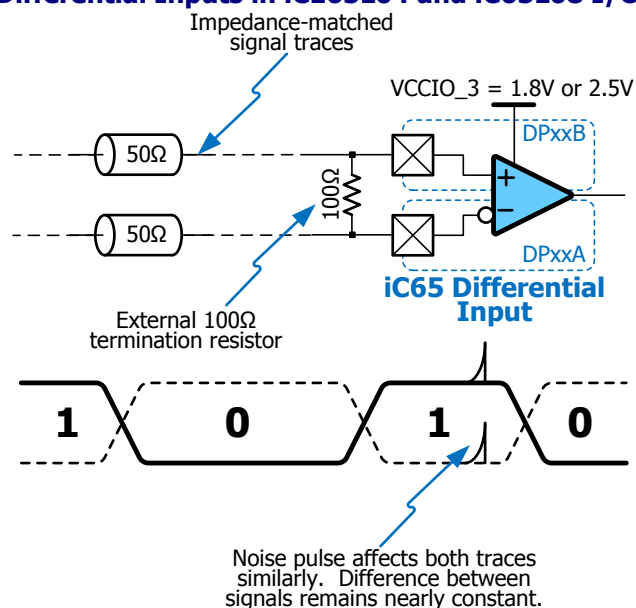


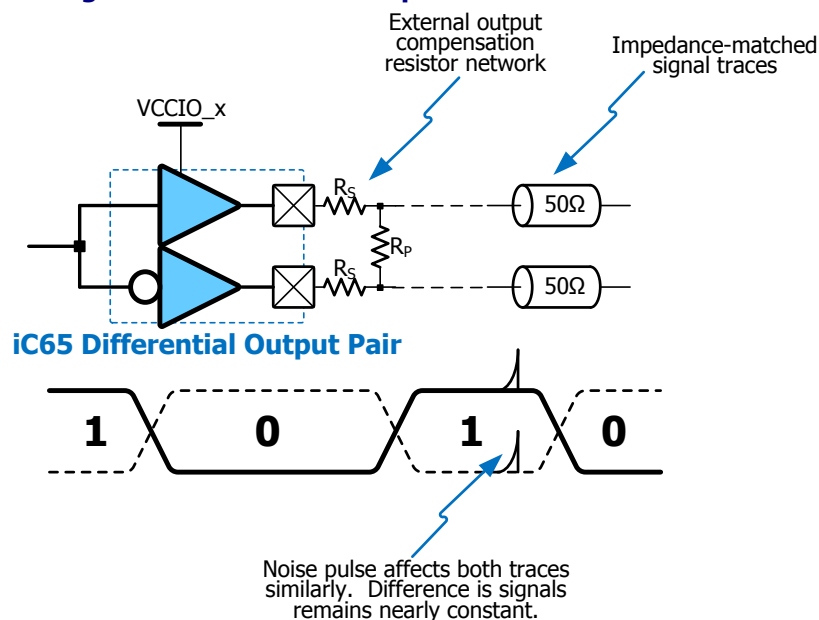
Figure 8: Differential Inputs in iCE65L04 and iCE65L08 I/O Bank 3



Differential Outputs in Any Bank

Differential outputs are built using a pair of single-ended PIO pins as shown in Figure 9. Each differential I/O pair requires a three-resistor termination network to adjust output characteristic to match those for the specific differential I/O standard. The output characteristics depend on the values of the parallel resistors (R_P) and series resistor (R_S). Differential outputs must be located in the same I/O tile.

Figure 9: Differential Output Pair



For electrical characteristics, see “Differential Outputs” on page 100.

The PIO pins that make up a differential output pair are indicated with a blue bounding box in the in the tables in “Die Cross Reference” starting on page 84.

Table 12 and Table 13 list the connections between a specific global buffer and the inputs on a Programmable I/O (PIO) pair. Although there is no direct connection between a global buffer and a PIO output, such a connection is possible by first connecting through a PLB LUT4 function. Again, all global buffers optionally drive all clock inputs. However, even-numbered global buffers optionally drive the clock-enable input on a PIO pair.



The PIO clock enable connect is different between the iCE65L01/iCE65L04 and iCE65L08.

Table 12: iCE65L01 & iCE65L04: Global Buffer (GBUF) Connections to Programmable I/O (PIO) Pair

Global Buffer	Output Connections	Input Clock	Output Clock	Clock Enable
GBUF0	No (connect through PLB LUT)	Yes	Yes	No
GBUF1		Yes	Yes	Yes
GBUF2		Yes	Yes	No
GBUF3		Yes	Yes	Yes
GBUF4		Yes	Yes	No
GBUF5		Yes	Yes	Yes
GBUF6		Yes	Yes	No
GBUF7		Yes	Yes	Yes

Table 13: iCE64L08: Global Buffer (GBUF) Connections to Programmable I/O (PIO) Pair

Global Buffer	Output Connections	Input Clock	Output Clock	Clock Enable
GBUF0	No (connect through PLB LUT)	Yes	Yes	Yes
GBUF1		Yes	Yes	No
GBUF2		Yes	Yes	Yes
GBUF3		Yes	Yes	No
GBUF4		Yes	Yes	Yes
GBUF5		Yes	Yes	No
GBUF6		Yes	Yes	Yes
GBUF7		Yes	Yes	No

Global Buffer Inputs

The iCE65 component has eight specialized GBIN/PIO pins that are optionally direct inputs to the global buffers, offering the best overall clock characteristics. As shown in Figure 15, each GBIN/PIO pin is a full-featured I/O pin but also provides a direct connection to its associated global buffer. The direct connection to the global buffer bypasses the iCEgate input-blocking latch and other PIO input logic. These special PIO pins are allocated two to an I/O Bank, a total of eight. These pins are labeled GBIN0 through GBIN7, as shown in Figure 14 and the pin locations for each GBIN input appear in Table 14.

Table 14: Global Buffer Input Ball/Pin Number by Package

Global Buffer Input (GBIN)	I/O Bank	VQ100	CB132	'L04 CB196	'L08 CB196	CB284
GBIN0	0	90	A6	A7	A7	E10
GBIN1		89	A7	E7	E7	E11
GBIN2	1	63	G14	F10	F10	L18
GBIN3		62	F14	G12	G12	K18
GBIN4	2	34	P8	L7	N8	V12
GBIN5		33	P7	P5	M7	V11
GBIN6	3	15	H1	H1	H1	M5
GBIN7		13	G1	G1	H3	L5

Automatic Global Buffer Insertion, Manual Insertion

The iCEcube development software automatically assigns high-fanout signals to a global buffer. However, to manually insert a global buffer input/global buffer (GBIN/GBUF) combination, use the **SB_IO_GB** primitive. To insert just a global buffer (GBUF), use the **SB_GB** primitive.

Global Hi-Z Control

The global high-impedance control signal, GHIZ, connects to all I/O pins on the iCE65 device. This GHIZ signal is automatically asserted throughout the configuration process, forcing all user-I/O pins into their high-impedance state. Similarly, the PIO pins can be forced into their high-impedance state via the JTAG controller.

Global Reset Control

The global reset control signal connects to all PLB and PIO flip-flops on the iCE65 device. The global reset signal is automatically asserted throughout the configuration process, forcing all flip-flops to their defined wake-up state. For PLB flip-flops, the wake-up state is always reset, regardless of the PLB flip-flop primitive used in the application. See [Table 3](#) for more information.

The PIO flip-flops are always reset during configuration, although the output flip-flop can be inverted before leaving the iCE65 device, as shown in [Figure 11](#).

RAM

Each iCE65 device includes multiple high-speed synchronous RAM blocks (RAM4K), each 4Kbit in size. As shown in [Table 16](#) a single iCE65 integrates between 16 to 96 such blocks. Each RAM4K block is generically a 256-word deep by 16-bit wide, two-port register file, as illustrated in [Figure 17](#). The input and output connections, to and from a RAM4K block, feed into the programmable interconnect resources.

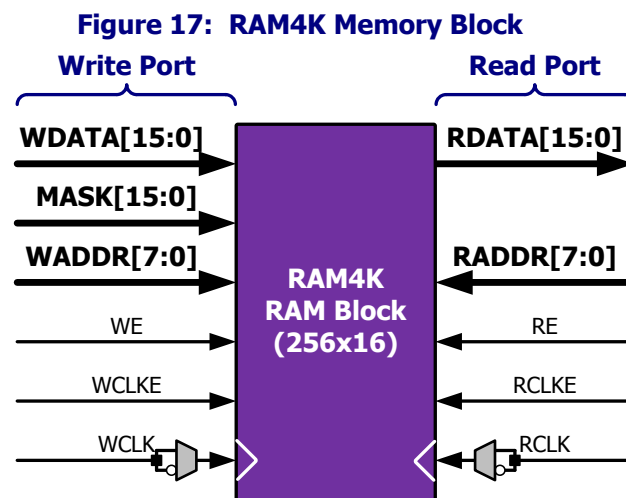


Table 16: RAM4K Blocks per Device

Device	RAM4K Blocks	Default Configuration	RAM Bits per Block	Block RAM Bits
iCE65L01	16	256 x 16	4K (4,096)	64K
iCE65L04	20			80K
iCE65L08	32			128K

Using programmable logic resources, a RAM4K block implements a variety of logic functions, each with configurable input and output data width.

- Random-access memory (RAM)
 - ◆ Single-port RAM with a common address, enable, and clock control lines
 - ◆ Two-port RAM with separate read and write control lines, address inputs, and enable

Device Configuration

As described in [Table 20](#), iCE65 components are configured for a specific application by loading a binary configuration bitstream image, generated by the Lattice development system. For high-volume applications, the bitstream image is usually permanently programmed in the on-chip NVCM. However, the bitstream image can also be stored external in a standard, low-cost commodity SPI serial Flash PROM. The iCE65 component can automatically load the image using the [SPI Master Configuration Interface](#). Similarly, the iCE65 configuration data can be downloaded from an external processor, microcontroller, or DSP processor using an SPI-like serial interface or an IEEE 1149 JTAG interface.

Table 20: iCE65 Device Configuration Modes

Mode	Analogy	Configuration Data Source
NVCM	ASIC	Internal, lowest-cost, secure, one-time programmable Nonvolatile Configuration Memory (NVCM)
SPI Flash	Microprocessor	External, low-cost, commodity, SPI serial Flash PROM
SPI Peripheral	Processor Peripheral	Configured by external device, such as a processor, microcontroller, or DSP using practically any data source, such as system Flash, a disk image, or over a network connection.
JTAG	JTAG	JTAG configuration requires sending a special command sequence on the SPI interface to enable JTAG configuration. Configuration is controlled by and external device.

Configuration Mode Selection

The iCE65 configuration mode is selected according to the following priority described below and illustrated in [Figure 20](#).

- After exiting the Power-On Reset (POR) state or when CRESET_B returns High after being held Low for 250 ns or more, the iCE65 FPGA samples the logical value on its SPI_SS_B pin. Like other programmable I/O pins, the SPI_SS_B pin has an internal pull-up resistor (see [Input Pull-Up Resistors on I/O Banks 0, 1, and 2](#)).
- If the [SPI_SS_B](#) pin is sampled as a logic '1' (High), then ...
 - ◆ Check if the iCE65 is enabled to configure from the Nonvolatile Configuration Memory (NVCM). If the iCE65 device has NVCM memory ('F' ordering code) but the NVCM is yet unprogrammed, then the iCE65 device is not enabled to configure from NVCM. Conversely, if the NVCM is programmed, the iCE65 device will configure from NVCM.
 - If enabled to configure from NVCM, the iCE65 device configures itself using NVCM.
 - If not enabled to configure from NVCM, then the iCE65 FPGA configures using the [SPI Master Configuration Interface](#).
- If the [SPI_SS_B](#) pin is sampled as a logic '0' (Low), then the iCE65 device waits to be configured from an external controller or from another iCE65 device in SPI Master Configuration Mode using an SPI-like interface.

Figure 24: SPI Release from Deep Power-down Command

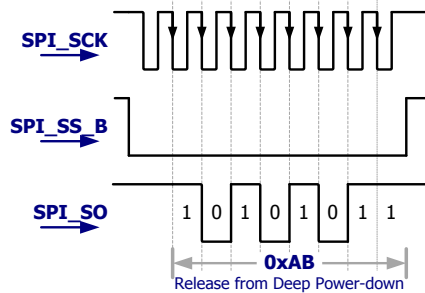
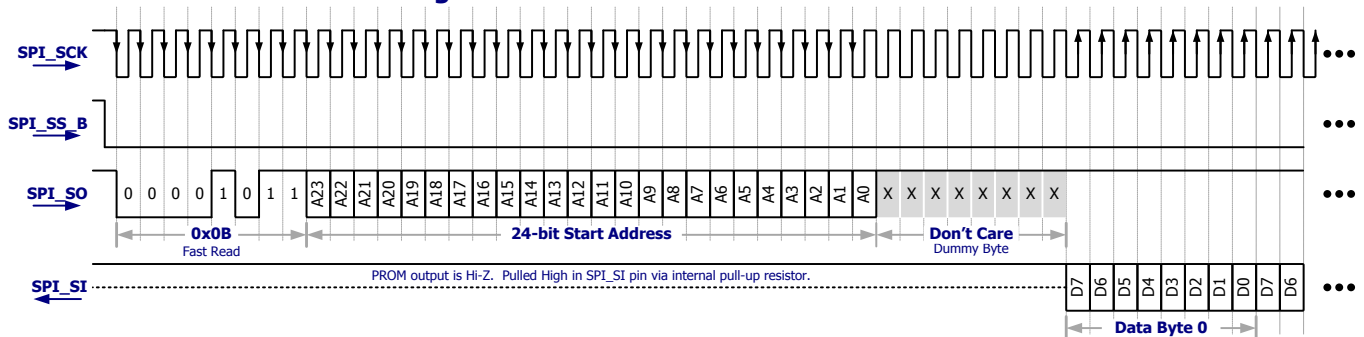


Figure 25 illustrates the next command issued by the iCE65 device. The iCE65 SPI interface again drives **SPI_SS_B** Low, followed by a Fast Read command, hexadecimal command code **0x0B**, followed by a 24-bit start address, transmitted on the **SPI_SO** output. The iCE65 device provides data on the falling edge of **SPI_SS_B**. Upon initial power-up, the start address is always **0x00_0000**. After waiting eight additional clock cycles, the iCE65 device begins reading serial data from the SPI PROM. Before presenting data, the SPI PROM's serial data output is high-impedance. The **SPI_SI** input pin has an internal pull-up resistor and sees high-impedance as logic '1'.

Figure 25: SPI Fast Read Command



The external SPI PROM supplies data on the falling edge of the iCE65 device's **SPI_SCK** clock output. The iCE65 device captures each PROM data value on the **SPI_SI** input, using the rising edge of the **SPI_SCK** clock signal. The SPI PROM data starts at the 24-bit address presented by the iCE65 device. PROM data is serially output, byte by byte, with most-significant bit, D7, presented first. The PROM automatically increments an internal byte counter as long as the PROM is selected and clocked.

After transferring the required number configuration data bits, the iCE65 device ends the Fast Read command by de-asserting its **SPI_SS_B** PROM select output, as shown in Figure 26. To conserve power, the iCE65 device then optionally issues a final Deep Power-down command, hexadecimal command code **0xB9**. After de-asserting the **SPI_SS_B** output, the SPI PROM enters its Deep Power-down mode. The final power-down step is optional; the application may use the SPI PROM and can skip this step, controlled by a configuration option.

Figure 26: Final Configuration Data, SPI Deep Power-down Command

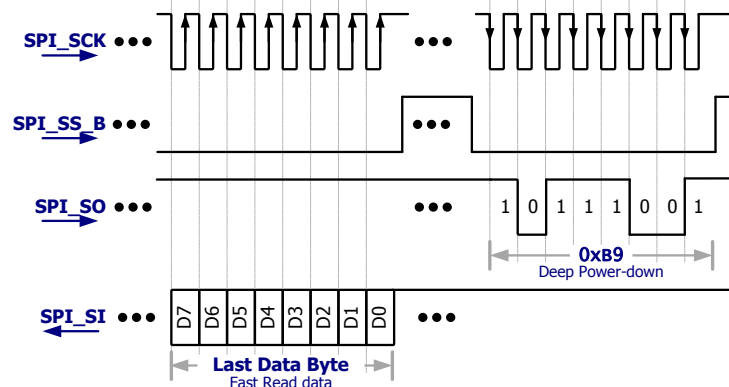
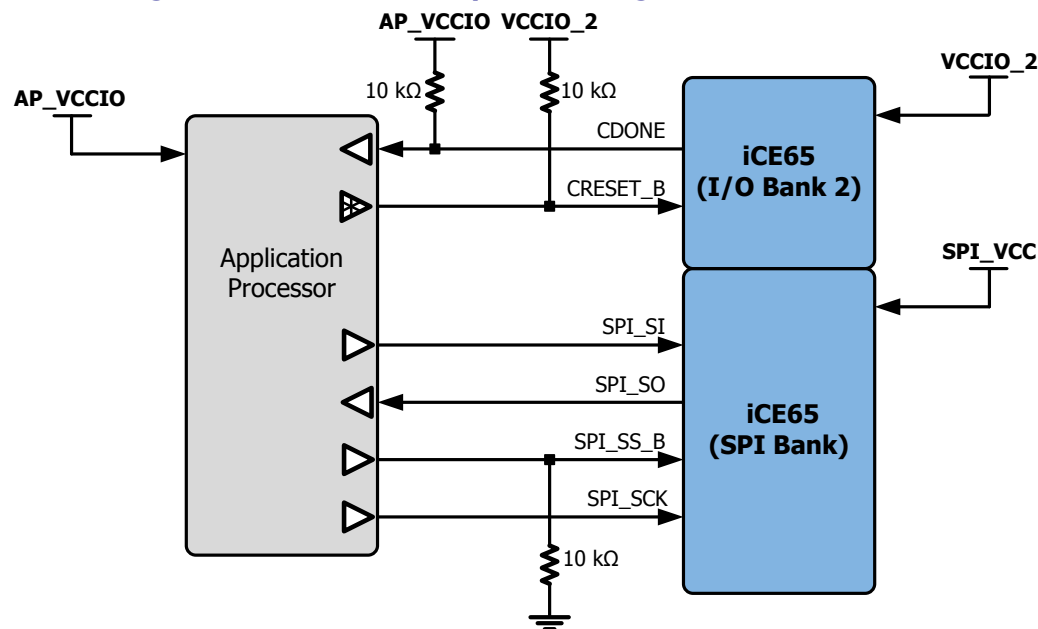


Figure 28: iCE65 SPI Peripheral Configuration Interface



The SPI control signals are defined in [Table 25](#).

Table 29: SPI Peripheral Configuration Interface Pins (SPI_SS_B Low when CRESET_B Released)

Signal Name	Direction	iCE65 I/O Supply	Description
CDONE	AP ← iCE65	VCCIO_2	Configuration Done output from iCE65. Connect to a 10kΩ pull-up resistor to the application processor I/O voltage, AP_VCC.
CRESET_B	AP → iCE65	VCCIO_2	Configuration Reset input on iCE65. Typically driven by AP using an open-drain driver, which also requires a 10kΩ pull-up resistor to VCCIO_2.
SPI_VCC	Supply	SPI_VCC	SPI Flash PROM voltage supply input.
SPI_SI	AP → iCE65	SPI_VCC	SPI Serial Input to the iCE65 FPGA, driven by the application processor.
SPI_SO	AP ← iCE65	SPI_VCC	SPI Serial Output from CE65 device to the application processor. Not actually used during SPI peripheral mode configuration but required if the SPI interface is also used to program the NVCN.
SPI_SS_B	AP → iCE65	SPI_VCC	SPI Slave Select output from the application processor. Active Low. Optionally hold Low prior to configuration using a 10kΩ pull-down resistor to ground.
SPI_SCK	AP → iCE65	SPI_VCC	SPI Slave Clock output from the application processor.

After configuration, the SPI port pins are available to the user-application as additional PIO pins, supplied by the SPI_VCC input voltage, essentially providing a fifth “mini” I/O bank.

Enabling SPI Configuration Interface

The optional 10 kΩ pull-down resistor on the SPI_SS_B signal ensures that the iCE65 FPGA powers up in the SPI peripheral mode. Optionally, the application processor drives the SPI_SS_B pin Low when CRESET_B is released, forcing the iCE65 FPGA into SPI peripheral mode.

SPI Peripheral Configuration Process

[Figure 29](#) illustrates the interface timing for the SPI peripheral mode and [Figure 30](#) outlines the resulting configuration process. The actual timing specifications appear in [Table 60](#). The application processor (AP) begins by driving the iCE65 CRESET_B pin Low, resetting the iCE65 FPGA. Similarly, the AP holds the iCE65’s SPI_SS_B pin Low. The AP must hold the CRESET_B pin Low for at least 200 ns. Ultimately, the AP either releases the CRESET_B pin and allows it to float High via the 10 kΩ pull-up resistor to VCCIO_2 or drives CRESET_B High. The iCE65 FPGA enters SPI peripheral mode when the CRESET_B pin returns High while the SPI_SS_B pin is Low.

Table 31 describes how to maintain voltage compatibility for two interface scenarios. The easiest interface is when the Application Processor's (AP) I/O supply rail and the iCE65's SPI and VCCIO_2 bank supply rails all connect to the same voltage. The second scenario is when the AP's I/O supply voltage is greater than the iCE65's VCCIO_2 supply voltage.

Table 31: CRESET_B and CDONE Voltage Compatibility

Condition	CRESET_B			CDONE Pull-up	Requirement
	Direct	Open-Drain	Pull-up		
VCCIO_AP = VCC_SPI VCCIO_AP = VCCIO_2	OK	OK with pull-up	Required if using open-drain output	Recommended	AP can directly drive CRESET_B High and Low although an open-drain output recommended is if multiple devices control CRESET_B. If using an open-drain driver, the CRESET_B input must include a 10 kΩ pull-up resistor to VCCIO_2. The 10 kΩ pull-up resistor to AP_VCCIO is also recommended.
AP_VCCIO > VCCIO_2	N/A	Required, requires pull-up	Required	Required	The AP must control CRESET_B with an open-drain output, which requires a 10 kΩ pull-up resistor to VCCIO_2. The 10 kΩ pull-up resistor to AP_VCCIO is required.

JTAG Boundary Scan Port

Overview

Each iCE65 device includes an IEEE 1149.1-compatible JTAG boundary-scan port. The port supports printed-circuit board (PCB) testing and debugging. It also provides an alternate means to configure the iCE65 device.

Signal Connections

The JTAG port connections are listed in Table 32.

Table 32: iCE65 JTAG Boundary Scan Signals

Signal Name	Direction	Description
TDI	Input	Test Data Input. Must be tied off to GND when unused. (no pull-up resistor)*
TMS	Input	Test Mode Select. Must be tied off to GND when unused. (no pull-up resistor)*
TCK	Input	Test Clock. Must be tied off to GND when unused. (no pull-up resistor)*
TDO	Output	Test Data Output.
TRST_B	Input	Test Reset, active Low. Must be Low during normal device operation. Must be High to enable JTAG operations.*

* Must be tied off to GND or VCCIO_1, else VCCIO_1 draws current.

Table 33 lists the ball/pin numbers for the JTAG interface by package code. The JTAG interface is available in select package types. The JTAG port is located in I/O Bank 1 along the right edge of the iCE65 device and powered by the VCCIO_1 supply inputs. Consequently, the JTAG interface uses the associated I/O standards for I/O Bank 1.

Table 33: JTAG Interface Ball/Pin Numbers by Package

JTAG Interface	VQ100	CB132	CB196	CB284
TDI	N/A	M12	M12	T16
TMS		P14	P14	V18
TCK		L12	L12	R16
TDO		N14	N14	U18
TRST_B		M14	M14	T18

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Ball Function	Ball Number	Pin Type	Bank
GND	K2	GND	GND
GND	K10	GND	GND
VCC	B6	VCC	VCC
VCC	F1	VCC	VCC
VCC	F11	VCC	VCC
VCC	K6	VCC	VCC
VPP_2V5	C10	VPP	VPP
VPP_FAST	A9	VPP	VPP

Ball Function	Ball Number	Pin Type	Bank
PIO2 (◆)	<i>ICE65L04:</i> N8 <i>ICE65L08:</i> L7	PIO	2
PIO2	N9	PIO	2
PIO2	N11	PIO	2
PIO2	N12	PIO	2
PIO2	N13	PIO	2
PIO2	P1	PIO	2
PIO2	P2	PIO	2
PIO2	P3	PIO	2
PIO2	P4	PIO	2
PIO2	P7	PIO	2
PIO2	P8	PIO	2
PIO2	P9	PIO	2
PIO2/CBSEL0	L9	PIO	2
PIO2/CBSEL1	P10	PIO	2
VCCIO_2	J9	VCCIO	2
VCCIO_2	M5	VCCIO	2
VCCIO_2	N10	VCCIO	2
PIO3/DP00A	C1	DPIO	3
PIO3/DP00B	B1	DPIO	3
PIO3/DP01A	D3	DPIO	3
PIO3/DP01B	C3	DPIO	3
PIO3/DP02A	D1	DPIO	3
PIO3/DP02B	D2	DPIO	3
PIO3/DP03A (◆)	<i>ICE65L04:</i> E1 <i>ICE65L08:</i> E2	DPIO	3
PIO3/DP03B (◆)	<i>ICE65L04:</i> E2 <i>ICE65L04:</i> E1	DPIO	3
PIO3/DP04A	D4	DPIO	3
PIO3/DP04B	E4	DPIO	3
PIO3/DP05A (◆)	<i>ICE65L04:</i> F3 <i>ICE65L08:</i> F4	DPIO	3
PIO3/DP05B (◆)	<i>ICE65L04:</i> F4 <i>ICE65L08:</i> F3	DPIO	3
PIO3/DP06A	F5	DPIO	3
PIO3/DP06B	E5	DPIO	3
PIO3/DP07A (◆)	<i>ICE65L04:</i> G2 <i>ICE65L08:</i> H4	DPIO	3
GBIN7/PIO3/DP07B (◆)	<i>ICE65L04:</i> G1 <i>ICE65L08:</i> H3	GBIN	3
GBIN6/PIO3/DP08A	H1	GBIN	3
PIO3/DP08B	H2	DPIO	3
PIO3/DP09A	G3	DPIO	3
PIO3/DP09B	G4	DPIO	3
PIO3/DP10A	J1	DPIO	3
PIO3/DP10B	J2	DPIO	3
PIO3/DP11A (◆)	<i>ICE65L04:</i> H4 <i>ICE65L08:</i> G1	DPIO	3
PIO3/DP11B (◆)	<i>ICE65L04:</i> H3 <i>ICE65L08:</i> G2	DPIO	3
PIO3/DP12A	K2	DPIO	3
PIO3/DP12B	J3	DPIO	3

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Ball Function	Ball Number	Pin Type	Bank
PIO3/DP13A	H5	DPIO	3
PIO3/DP13B	G5	DPIO	3
PIO3/DP14A	L1	DPIO	3
PIO3/DP14B	L2	DPIO	3
PIO3/DP15A	M1	DPIO	3
PIO3/DP15B	M2	DPIO	3
PIO3/DP16A (◆)	<i>iCE65L04</i> : K3 <i>iCE65L08</i> : K4	DPIO	3
PIO3/DP16B (◆)	<i>iCE65L08</i> : K4 <i>iCE65L08</i> : K3	DPIO	3
PIO3/DP17A	N1	DPIO	3
PIO3/DP17B	N2	DPIO	3
VCCIO_3	E3	VCCIO	3
VCCIO_3	J6	VCCIO	3
VCCIO_3	K1	VCCIO	3
PIOS/SPI_SO	M11	SPI	SPI
PIOS/SPI_SI	P11	SPI	SPI
PIOS/SPI_SCK	P12	SPI	SPI
PIOS/SPI_SS_B	P13	SPI	SPI
SPI_VCC	L11	SPI	SPI
GND	A9	GND	GND
GND	B12	GND	GND
GND	C2	GND	GND
GND	F1	GND	GND
GND	F7	GND	GND
GND	G7	GND	GND
GND	G8	GND	GND
GND	G9	GND	GND
GND	H6	GND	GND
GND	H7	GND	GND
GND	H8	GND	GND
GND	J5	GND	GND
GND	J8	GND	GND
GND	J14	GND	GND
GND	K10	GND	GND
GND	L3	GND	GND
GND	P6	GND	GND
VCC	B7	VCC	VCC
VCC	F2	VCC	VCC
VCC	F8	VCC	VCC
VCC	G6	VCC	VCC
VCC	H9	VCC	VCC
VCC	J4	VCC	VCC
VCC	J7	VCC	VCC
VCC	K13	VCC	VCC
VCC	N7	VCC	VCC
VPP_2V5	A14	VPP	VPP
VPP_FAST	A13	VPP	VPP

Pinout Differences between iCE65L04 and iCE65L08 in CB196 Package

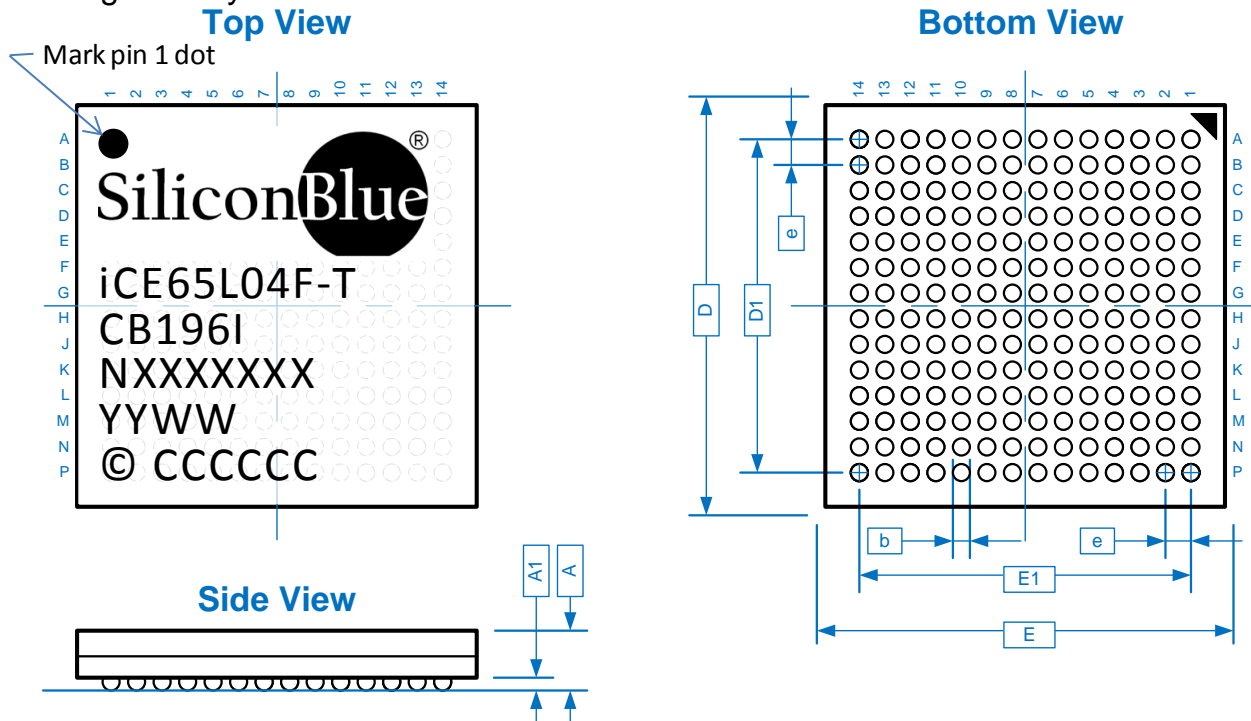
Table 43 lists the package balls that are different between the pinouts for iCE65L04 and the iCE65L08 in the CB196 package. The table also describes the functional differences between these pins, which is critical when designing a CB196 footprint that supports both the iCE65L04 and the iCE65L08 devices. In some cases, only the differential inputs are swapped; single-ended I/Os are not affected. A swapped differential pair can be inverted internally for functional equivalence. In other cases, a global buffer input is swapped with another PIO pin in the same bank.

Table 43: Pinout Differences between iCE65L04 and iCE65L08 in CB196 Package

Ball Number	iCE65L04	iCE65L08	Functional Difference
E1	PIO3/DP03A	PIO3/DP03B	Differential inputs swapped, single-ended I/Os not affected
E2	PIO3/DP03B	PIO3/DP03A	
F3	PIO3/DP05A	PIO3/DP05B	Differential inputs swapped, single-ended I/Os not affected
F4	PIO3/DP05B	PIO3/DP05A	
G1	GBIN7/PIO3/DP07B	PIO3/DP11A	Global buffer input GBIN7 and its associated differential input is swapped with another differential pair in I/O Bank 3
G2	PIO3/DP07A	PIO3/DP11B	
H3	PIO3/DP11B	GBIN7/PIO3/DP07B	
H4	PIO3/DP11A	PIO3/DP07A	
K3	PIO3/DP16A	PIO3/DP16B	Differential inputs swapped, single-ended I/Os not affected
K4	PIO3/DP16B	PIO3/DP16A	
L7	GBIN4/PIO2	PIO2	Global buffer input GBIN4 swapped with another PIO pin in I/O Bank 2
N8	PIO2	GBIN4/PIO2	
M7	PIO2	GBIN5/PIO2	Global buffer input GBIN5 swapped with another PIO pin in I/O Bank 2
P5	GBIN5/PIO2	PIO2	

Figure 47:
(a) iCE65L04 CB196 Package Mechanical Drawing

CB196: 8 x8 mm, 196-ball, 0.5 mm ball-pitch, fully-populated, chip-scale ball grid array



Description	Symbol	Min.	Nominal	Max.	Units
Number of Ball Columns	X		14		Columns
Number of Ball Rows	Y		14		Rows
Number of Signal Balls	n		196		Balls
Body Size	X	E	7.90	8.00	mm
	Y	D	7.90	8.00	
Ball Pitch		e	—	0.50	
Ball Diameter		b	0.27	—	
Edge Ball Center to Center	X	E1	—	6.50	
	Y	D1	—	6.50	
Package Height		A	—	1.00	
Stand Off		A1	0.16	—	

Top Marking Format

Line	Content	Description
1	Logo	Logo
2	iCE65L04F	Part number
	-T	Power/Speed
3	CB196I	Package type
	ENG	Engineering
4	NXXXXXXX	Lot Number
5	YYWW	Date Code
6	© CCCCCC	Country

Thermal Resistance

Junction-to-Ambient θ_{JA} (°C/W)	
0 LFM	200 LFM
42	34

Ball Function	Ball Number	Pin Type by Device		Bank	CB132 Ball Equivalent
	ice65L04 ice65L08	ice65L04	ice65L08		
PIO1	L15	PIO	PIO	1	G11
PIO1	L16	PIO	PIO	1	G12
PIO1 (●)	L22	N.C.	PIO	1	—
PIO1	M15	PIO	PIO	1	H11
PIO1	M16	PIO	PIO	1	H12
PIO1	M20	PIO	PIO	1	—
PIO1 (●)	M22	N.C.	PIO	1	—
PIO1	N15	PIO	PIO	1	J11
PIO1	N16	PIO	PIO	1	J12
PIO1	N22	PIO	PIO	1	—
PIO1	P15	PIO	PIO	1	K11
PIO1	P16	PIO	PIO	1	K12
PIO1	P18	PIO	PIO	1	K14
PIO1	P20	PIO	PIO	1	—
PIO1	P22	PIO	PIO	1	—
PIO1	R18	PIO	PIO	1	L14
PIO1	R20	PIO	PIO	1	—
PIO1	R22	PIO	PIO	1	—
PIO1	T20	PIO	PIO	1	—
PIO1	T22	PIO	PIO	1	—
PIO1	U20	PIO	PIO	1	—
PIO1 (●)	U22	N.C.	PIO	1	—
PIO1	V20	PIO	PIO	1	—
PIO1 (●)	V22	N.C.	PIO	1	—
PIO1	W20	PIO	PIO	1	—
PIO1 (●)	W22	N.C.	PIO	1	—
PIO1 (●)	Y22	N.C.	PIO	1	—
TCK	R16	JTAG	JTAG	1	L12
TDI	T16	JTAG	JTAG	1	M12
TDO	U18	JTAG	JTAG	1	N14
TMS	V18	JTAG	JTAG	1	P14
TRST_B	T18	JTAG	JTAG	1	M14
VCCIO_1	H22	VCCIO	VCCIO	1	—
VCCIO_1	J20	VCCIO	VCCIO	1	—
VCCIO_1	K13	VCCIO	VCCIO	1	F9
VCCIO_1	M18	VCCIO	VCCIO	1	H14
CDONE	T14	CONFIG	CONFIG	2	M10
CRESET_B	R14	CONFIG	CONFIG	2	L10
GBIN4/PIO2	V12	GBIN	GBIN	2	P7
GBIN5/PIO2	V11	GBIN	GBIN	2	P8
PIO2	R8	PIO	PIO	2	L4
PIO2	R9	PIO	PIO	2	L5
PIO2	R10	PIO	PIO	2	L6
PIO2	R11	PIO	PIO	2	L7
PIO2	R12	PIO	PIO	2	L8
PIO2	T7	PIO	PIO	2	M3
PIO2	T8	PIO	PIO	2	M4
PIO2	T10	PIO	PIO	2	M6
PIO2	T11	PIO	PIO	2	M7
PIO2	T12	PIO	PIO	2	M8

iCE65 Ultra Low-Power mobileFPGA™ Family

Ball Function	Ball Number	Pin Type by Device		Bank	CB132 Ball Equivalent
	iCE65L04 iCE65L08	iCE65L04	iCE65L08		
PIO2	T13	PIO	PIO	2	M9
PIO2	V6	PIO	PIO	2	P2
PIO2	V7	PIO	PIO	2	P3
PIO2	V8	PIO	PIO	2	P4
PIO2	V9	PIO	PIO	2	P5
PIO2	V13	PIO	PIO	2	P9
PIO2	Y4	PIO	PIO	2	—
PIO2	Y5	PIO	PIO	2	—
PIO2	Y6	PIO	PIO	2	—
PIO2	Y7	PIO	PIO	2	—
PIO2	Y9	PIO	PIO	2	—
PIO2	Y10	PIO	PIO	2	—
PIO2	Y13	PIO	PIO	2	—
PIO2	Y14	PIO	PIO	2	—
PIO2	Y15	PIO	PIO	2	—
PIO2	Y17	PIO	PIO	2	—
PIO2	Y18	PIO	PIO	2	—
PIO2	Y19	PIO	PIO	2	—
PIO2	Y20	PIO	PIO	2	—
PIO2	AB2	PIO	PIO	2	—
PIO2 (●)	AB3	N.C.	PIO	2	—
PIO2 (●)	AB4	N.C.	PIO	2	—
PIO2	AB6	PIO	PIO	2	—
PIO2	AB7	PIO	PIO	2	—
PIO2	AB8	PIO	PIO	2	—
PIO2	AB9	PIO	PIO	2	—
PIO2	AB10	PIO	PIO	2	—
PIO2	AB11	PIO	PIO	2	—
PIO2	AB12	PIO	PIO	2	—
PIO2	AB13	PIO	PIO	2	—
PIO2	AB14	PIO	PIO	2	—
PIO2	AB15	PIO	PIO	2	—
PIO2 (●)	AB16	N.C.	PIO	2	—
PIO2 (●)	AB17	N.C.	PIO	2	—
PIO2 (●)	AB18	N.C.	PIO	2	—
PIO2 (●)	AB19	N.C.	PIO	2	—
PIO2 (●)	AB20	N.C.	PIO	2	—
PIO2 (●)	AB21	N.C.	PIO	2	—
PIO2 (●)	AB22	N.C.	PIO	2	—
PIO2/CBSEL0	R13	PIO	PIO	2	L9
PIO2/CBSEL1	V14	PIO	PIO	2	P10
VCCIO_2	N13	VCCIO	VCCIO	2	J9
VCCIO_2	T9	VCCIO	VCCIO	2	M5
VCCIO_2	Y11	VCCIO	VCCIO	2	—
PIO3/DP00A	F5	DPIO	DPIO	3	B1
PIO3/DP00B	G5	DPIO	DPIO	3	C1
PIO3/DP01A	G7	DPIO	DPIO	3	C3
PIO3/DP01B	H7	DPIO	DPIO	3	D3
PIO3/DP02A	H8	DPIO	DPIO	3	D4
PIO3/DP02B	J8	DPIO	DPIO	3	E4

iCE65L04 Pad Name	DiePlus				Pad	X (μm)	Y (μm)
	VQ100	CB132	CB196	CB284			
CRESET_B	44	L10	L10	R14	121	2,625.00	139.20
PIOS_00/SPI_SO	45	M11	M11	T15	122	2,690.00	37.20
PIOS_01/SPI_SI	46	P11	P11	V15	123	2,740.00	139.20
GND	47	—	P6	Y16	124	2,790.00	37.20
PIOS_02/SPI_SCK	48	P12	P12	V16	125	2,840.00	139.20
PIOS_03/SPI_SS_B	49	P13	P13	V17	126	2,890.00	37.20
SPI_VCC	50	L11	L11	R15	127	2,990.00	37.20
TDI	N/A	M12	M12	T16	128	3,610.80	342.00
TMS	N/A	P14	P14	V18	129	3,712.80	392.00
TCK	N/A	L12	L12	R16	130	3,610.80	442.00
TDO	N/A	N14	N14	U18	131	3,712.80	492.00
TRST_B	N/A	M14	M14	T18	132	3,610.80	542.00
PIO1_00	51	L14	K11	R18	133	3,712.80	592.00
PIO1_01	52	K12	L13	P16	134	3,610.80	642.00
PIO1_02	53	K11	K12	P15	135	3,712.80	692.00
PIO1_03	54	K14	M13	P18	136	3,610.80	727.00
GND	55	J14	J14	N18	137	3,712.80	762.00
GND	55	J14	J14	N18	138	3,610.80	797.00
PIO1_04	56	J12	J10	N16	139	3,712.80	832.00
PIO1_05	57	J11	L14	N15	140	3,610.80	867.00
VCCIO_1	58	H14	H14	M18	141	3,712.80	902.00
VCCIO_1	—	—	—	—	142	3,610.80	937.00
PIO1_06	59	H12	J11	M16	143	3,712.80	972.00
PIO1_07	60	H11	K14	M15	144	3,610.80	1,007.00
PIO1_08	—	—	H10	W20	145	3,712.80	1,042.00
PIO1_09	—	—	J13	V20	146	3,610.80	1,077.00
PIO1_10	—	—	J12	U20	147	3,712.80	1,112.00
VCC	61	H9	N7	M13	148	3,610.80	1,147.00
VCC	—	—	—	—	149	3,712.80	1,182.00
PIO1_11	—	—	H13	T22	150	3,610.80	1,217.00
PIO1_12	—	—	H12	R22	151	3,712.80	1,252.00
PIO1_13	—	—	—	P22	152	3,610.80	1,287.00
PIO1_14	—	—	—	N22	153	3,712.80	1,322.00
PIO1_15	—	—	G13	T20	154	3,610.80	1,357.00
PIO1_16	—	—	H11	R20	155	3,712.80	1,392.00
PIO1_17	—	—	G14	P20	156	3,610.80	1,427.00
GND	—	—	K10	N20	157	3,712.80	1,462.00
GND	—	—	—	—	158	3,610.80	1,497.00
PIO1_18	—	—	G10	M20	159	3,712.80	1,532.00
GBIN3/PIO1_19	62	F14	G12	K18	160	3,610.80	1,567.00
GBIN2/PIO1_20	63	G14	F10	L18	161	3,712.80	1,602.00
PIO1_21	—	—	F14	K20	162	3,610.80	1,637.00
VCCIO_1	—	—	H14	J20	163	3,712.80	1,672.00
VCCIO_1	—	—	—	—	164	3,610.80	1,707.00
PIO1_22	—	—	F13	H20	165	3,712.80	1,742.00
PIO1_23	—	—	D13	G20	166	3,610.80	1,777.00

Electrical Characteristics

All parameter limits are specified under worst-case supply voltage, temperature, and processing conditions.

Absolute Maximum Ratings

Stresses beyond those listed under Table 47 may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions beyond those listed under the Recommended Operating Conditions is not implied. Exposure to absolute maximum conditions for extended periods of time adversely affects device reliability.

Table 47: Absolute Maximum Ratings

Symbol	Description	Min	Max	Units
VCC	Core supply Voltage	−0.5	1.42	V
VPP_2V5	VPP_2V5 NVCM programming and operating supply			V
VPP_FAST	Optional fast NVCM programming supply			V
VCCIO_0 VCCIO_1 VCCIO_2 SPI_VCC	I/O bank supply voltage (I/O Banks 0, 1, and 2 plus SPI interface)	−0.5	4.00	V
VCCIO_3	I/O Bank 3 supply voltage	−0.5	iCE65L01: 4.00 iCE65L04/08: 3.6	V
VIN_0 VIN_1 VIN_2 VIN_SPI	Voltage applied to PIO pin within a specific I/O bank (I/O Banks 0, 1, and 2 plus SPI interface)	−1.0	5.5	V
VIN_3 VIN_VREF	Voltage applied to PIO pin within I/O Bank 3	−0.5	iCE65L01: 4.00 iCE65L04/08: 3.6	V
IOUT	DC output current per pin	—	20	mA
T_J	Junction temperature	−55	125	°C
T_{STG}	Storage temperature, no bias	−65	150	°C

Recommended Operating Conditions

Table 48: Recommended Operating Conditions

Symbol	Description		Minimum	Nominal	Maximum	Units
VCC	Core supply voltage	–L: Ultra-Low Power mode	0.95	1.00	1.05	V
		–L: Low Power	1.14	1.20	1.26	V
		–T: High Performance				
VPP_2V5	VPP_2V5 NVCM programming and operating supply	Release from Power-on Reset	1.30	—	3.47	V
		Configure from NVCM	2.30	—	3.47	V
		NVCM programming	2.30	—	3.00	V
VPP_FAST	Optional fast NVCM programming supply		Leave unconnected in application			
SPI_VCC	SPI interface supply voltage		1.71	—	3.47	V
VCCIO_0 VCCIO_1 VCCIO_2 VCCIO_3 SPI_VCC	I/O standards, all banks*	LVC MOS33	3.14	3.30	3.47	V
		Non-standard voltage: in between 2.5V and 3.3V use LVC MOS25 in iCEcube2	Nominal –5%	2.5< Nominal <3.3	Nominal +5%	V
		LVC MOS25, LVDS	2.38	2.50	2.63	V
		LVC MOS18, SubLVDS	1.71	1.80	1.89	V
		LVC MOS15	1.43	1.50	1.58	V
VCCIO_3	I/O standards only available in iCE65L04/08 I/O Bank 3*	SSTL2	2.38	2.50	2.63	V
		SSTL18	1.71	1.80	1.89	V
		MDDR	1.71	1.80	1.89	V
T _A	Ambient temperature	Commercial (C)	0	—	70	°C
		Industrial (I)	–40	—	85	°C
T _{PROG}	NVCM programming temperature		10	25	30	°C

NOTE:

VPP_FAST is only used for fast production programming. Leave floating or unconnected in application. When the iCE65 device is active, VPP_2V5 must be connected to a valid voltage.

Revision History

Version	Date	Description
2.42	30-MAR-2012	Changed company name. Updated Table 1
2.41	1-AUG-2011	Added VQ100 marking for NVCM programming.
2.4	13-MAY-2011	Added L01 CB121 package Figure 39 . Added note “else VCCIO_1 draws current” to JTAG inputs TCK, TDI and TMS do not have the input pull-up resistor and must be tied off to GND when unused, Table 32 . Input pin leakage current Table 49 split by bank. QN84 package drawing, Figure 35 , added note “underside metal is at ground potential”, increased thermal resistance. Added Marking Format and Thermal resistance to CB81 Packag Mechanical Drawing Figure 33 . Added coplanarity specification to VQ100 Package Mechanical Drawing Figure 37
2.3	18-OCT-2010	Added L01 CB81 and L08 CB132 packages.
2.2.3	12-OCT-2010	Changed Figure 29: Application Processor Waveforms for SPI Peripheral Mode Configuration Process and Table 60 from 300 µs CRESET_B to 800 µs for iCE65L01/04 and 1200 µs for iCE65L08.
2.2.2	8-OCT-2010	Added iCE65L04 marking specification to Figure 47 CB196 Package Mechanical Drawing.
2.2.1	5-OCT-2010	Changed FSPI_SCK from 0.125 MHz to 1 MHz in SPI Peripheral Configuration Interface and in Table 60 .
2.2	6-AUG-2010	Programmable Interconnect section removed.
2.1.1	26-MAY-2010	Switched labels on Figure 53 LVCMOS Output High, VCCIO = 1.8V with VCCIO = 2.5V.
2.1	15-MAR-2010	Added JTAG unused input tie off guideline. Added marking specification and thermal characteristics to package drawings. Added production datasheet for iCE65L01 with timing update, including QN84, VQ100 and CB132. Added NVCM shut-off on SPI configuration. Added non-standard VCCIO operating conditions. Increased the minimum voltage supply specification for LVCMOS33 to 3.14V in Table 48 .
2.0.1	12-NOV-2009	Recommended Operation Conditions, Table 47 , replaced junction with ambient.
2.0	14-SEPT-2009	Finalized production data sheet for iCE65L04 and iCE65L08. Improved SubLVDS input specification V _{ICM} in Table 52 . CS63 and CC72 packages removed and placed in iCE DiCE KGD, Known Good Die datasheet. Added “IBIS Models for I/O Banks 0, 1, 2 and the SPI Bank”. Added “Printed Circuit Board Layout Information”.
1.5.1	13-JUL-2009	Updated the text in “ SPI PROM Requirements ” section. Minor label change in Figure 48 .
1.5	20-JUN-2009	Updated timing information and added –T high-speed device option (affected Figure 2 , Table 48 , Table 54 , Table 55 , Table 56 , and Table 61). Added support for 3.3V LVCMOS I/Os in I/O Bank 3 (affected Figure 7 , Table 5 , Table 7 , Table 8 , Table 47 , Table 48 , and Table 51). Added a section about the SPI Peripheral Configuration Interface and timing in Table 60 . Added a warning that a Warm Boot operation can only jump to another configuration image that has Warm Boot disabled. Updated configuration image size and configuration time for the iCE65L02 in Table 27 and Table 58 . Reduced the minimum voltage supply specification for LVCMOS33 to 2.7V in Table 48 . Added information about which power rails can be disconnected without effecting the Power-On Reset (POR) circuit and clarified description of VPP_2V5 pin in Table 36 . Added I/O characterization curves (Figure 52 , Figure 53 , and Figure 54). Minor changes to Figure 20 and Figure 21 . Changed timing per Figures 54-58 and Tables 55-57 .
1.4.4	25-MAR-2009	Clarified the voltage requirements for the VPP_2V5 pin in Table 36 and notes under Table 48 .
1.4.3	9-MAR-2009	Removed volatile-only (-V) product offering from Figure 2 . Corrected NC on ball V22, removed it for ball T22 on CB284 package (Figure 48).
1.4.2	27-FEB-2009	Updated Table 14 , Table 23 , Table 26 , Table 30 , Table 33 , Table 35 , and Table 46 . Updated I/O Bank 3 information in Table 7 and Table 48 .
1.4.1	24-FEB-2009	Based on characterization data, reduced 32KHz operating current by 40% in Table 1 , Table 61 , and Figure 1 . Corrected that SSTL18 standards require VREF pin in Table 7 . Correct ball numbers for GBIN4/GBIN5 for CS110 package.
1.4	9-FEB-2009	Added footprint and pinout information for the VQ100 Very-thin Quad Flat Package. Added footprint for iCE65L08 in CB196 (Figure 46) and added Table 43 showing the differences between the ‘L04 and ‘L08 in the CB196 package. Unified the package footprint nomenclature in the Package and Pinout Information section. Added note to Global Buffer Inputs that the differential clock direct input is not available on the CB132 package. Added tables showing the ball/pin number for various control functions, by package (Table 14 , Table 23 , Table 26 , Table 30 , and Table 33). Corrected the GBIN/GBUF designations. GBIN4 and GBIN5 were swapped as were GBIN6 and GBIN7. This change affected all pinout tables and footprint diagrams. Updated and corrected “ Differential Global Buffer Input .” Tested and corrected the clock-enable and reset connections between global buffers and various resources (Table 11 , Table 12 , and Table 13). Added “ Automatic Global Buffer Insertion , Manual Insertion .” Added “ Die Cross Reference ” section. Improved industrial temperature range by lowering